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September 1983 Revised May 2005

# MM74HC373 3-STATE Octal D-Type Latch

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#### MM74HC373 3-STATE Octal D-Type Latch

#### **General Description**

The MM74HC373 high speed octal D-type latches utilize advanced silicon-gate CMOS technology. They possess the high noise immunity and low power consumption of standard CMOS integrated circuits, as well as the ability to drive 15 LS-TTL loads. Due to the large output drive capability and the 3-STATE feature, these devices are ideally suited for interfacing with bus lines in a bus organized system.

When the LATCH ENABLE input is HIGH, the Q outputs will follow the D inputs. When the LATCH ENABLE goes LOW, data at the D inputs will be retained at the outputs until LATCH ENABLE returns HIGH again. When a high logic level is applied to the OUTPUT CONTROL input, all outputs go to a high impedance state, regardless of what signals are present at the other inputs and the state of the storage elements.

The 74HC logic family is speed, function, and pin-out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to  $\rm V_{CC}$  and ground.

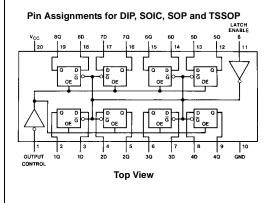
# Features Typical propagation delay: 18 ns

- Wide operating voltage range: 2 to 6 volts
   Low input current: 1 μA maximum
- Low input current: 1 μA maximum
   Low quiescent current: 80 μA maximum (74 Series)
- Output drive capability: 15 LS-TTL loads

#### **Ordering Code:**

20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
20-Lead Small Outline Package (SOP) EIA TYPE II 5 3mm Wide
20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

#### **Connection Diagram**



#### **Truth Table**

Output	put Latch Data		373
Control	Enable		Output
L	Н	Н	Н
L	н	L	L
L	L	х	Q <sub>0</sub>
Н	Х	Х	Z

H = HIGH Level L = LOW Level

 $\mathbf{Q}_0 = \text{Level}$  of output before steady-state input conditions were established. Z = High Impedance

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#### Absolute Maximum Ratings(Note 1) (Note 2)

# Recommended Operating Conditions

Supply Voltage (V <sub>CC</sub> )	-0.5 to +7.0V
DC Input Voltage (V <sub>IN</sub> )	-1.5 to V <sub>CC</sub> +1.5V
DC Output Voltage (V <sub>OUT</sub> )	–0.5 to V <sub>CC</sub> +0.5V
Clamp Diode Current (I <sub>IK</sub> , I <sub>OK</sub> )	±20 mA
DC Output Current, per pin (I <sub>OUT</sub> )	±35 mA
DC $V_{CC}$ or GND Current, per pin (I_{CC})	±70 mA
Storage Temperature Range (T <sub>STG</sub> )	-65°C to +150°C
Power Dissipation (P <sub>D</sub> )	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T <sub>L</sub> )	
(Soldering 10 seconds)	260°C

	Min	Max	Units
Supply Voltage (V <sub>CC</sub> )	2	6	V
DC Input or Output Voltage			
(V <sub>IN</sub> ,V <sub>OUT</sub> )	0	$V_{CC}$	V
Operating Temperature Range $(T_A)$	-40	+85	°C
Input Rise or Fall Times			
$(t_{r}, t_{f}) V_{CC} = 2.0V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns
Note 1: Absolute Maximum Ratings are those	values b	eyond whi	ch dam-

age to the device may occur. Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

#### **DC Electrical Characteristics**

Symbol	Parameter	Conditions	Vcc	T <sub>A</sub> = 25°C		$T_A = -40$ to $85^\circ$ C	$T_A = -55$ to $125^{\circ}C$	Units
Symbol		Conditions	*cc	Тур		Guaranteed L	imits	Units
V <sub>IH</sub>	Minimum HIGH Level		2.0V		1.5	1.5	1.5	V
	Input Voltage		4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
VIL	Maximum LOW Level		2.0V		0.5	0.5	0.5	V
	Input Voltage		4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V <sub>OH</sub>	Minimum HIGH Level	$V_{IN} = V_{IH} \text{ or } V_{IL}$						
	Output Voltage	I <sub>OUT</sub>   ≤ 20 μA	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$						
		I <sub>OUT</sub>   ≤ 6.0 mA	4.5V	4.2	3.98	3.84	3.7	V
		I <sub>OUT</sub>   ≤ 7.8 mA	6.0V	5.7	5.48	5.34	5.2	V
V <sub>OL</sub>	Maximum LOW Level	$V_{IN} = V_{IH} \text{ or } V_{IL}$						
	Output Voltage	I <sub>OUT</sub>   ≤ 20 μA	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$						
		$ I_{OUT}  \le 6.0 \text{ mA}$	4.5V	0.2	0.26	0.33	0.4	V
		$ I_{OUT}  \le 7.8 \text{ mA}$	6.0V	0.2	0.26	0.33	0.4	V
I <sub>IN</sub>	Maximum Input	V <sub>IN</sub> = V <sub>CC</sub> or GND	6.0V		±0.1	±1.0	±1.0	μA
	Current							
I <sub>OZ</sub>	Maximum 3-STATE	$V_{IN} = V_{IH} \text{ or } V_{IL}, \text{ OC} = V_{IH}$	6.0V		±0.5	±5	±10	μΑ
	Output Leakage	$V_{OUT} = V_{CC} \text{ or } GND$						
	Current							
I <sub>CC</sub>	Maximum Quiescent	$V_{IN} = V_{CC}$ or GND	6.0V		8.0	80	160	μA
	Supply Current	I <sub>OUT</sub> = 0 μA						

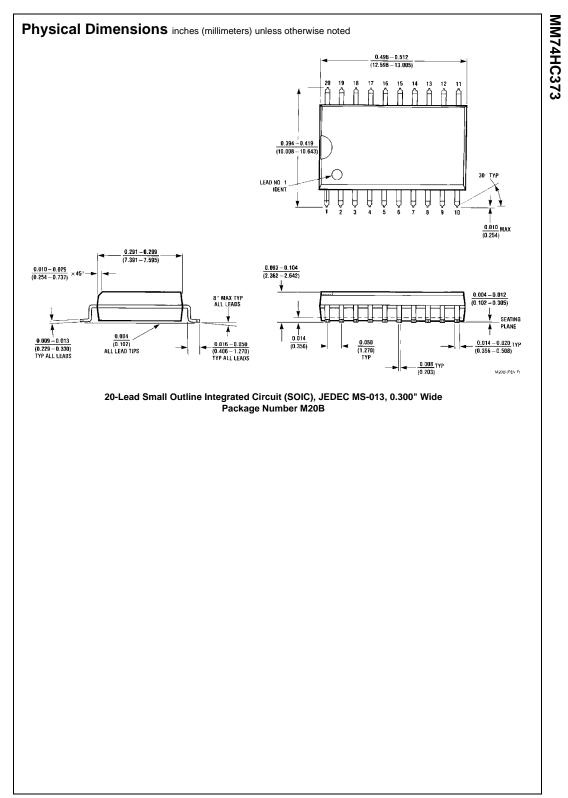
Note 4: For a power supply of 5V  $\pm$ 10% the worst case output voltages (V<sub>OH</sub>, and V<sub>OL</sub>) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V<sub>IH</sub> and V<sub>IL</sub> occur at V<sub>CC</sub> = 5.5V and 4.5V respectively. (The V<sub>IH</sub> value at 5.5V is 3.85V.) The worst case leakage current (I<sub>IN</sub>, I<sub>CC</sub>, and I<sub>O2</sub>) occur for CMOS at the higher voltage and so the 6.0V values should be used.

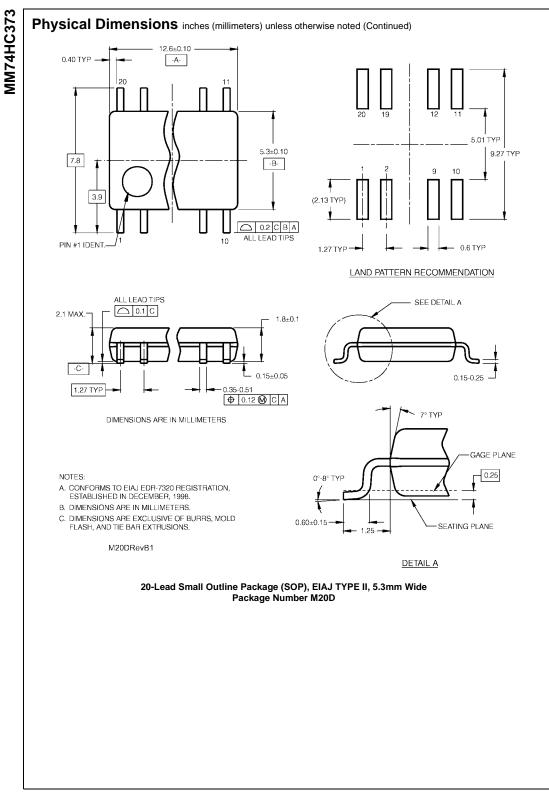
	V, $T_{A} = 25^{\circ}C$ , $t_{r} = t_{f} = 6$ ns					1		Guaranteed		
Symb	ol Parame	ter		Cond	litions		Тур	Limit	Un	its
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation	pagation Delay, Data to Q		$P Q C_L = 45  pF$			18	25	n	S
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation	Delay, LE to Q	C <sub>L</sub> = 45	рF			21	30	n	S
t <sub>PZH</sub> , t <sub>PZL</sub>	Maximum Output Enal	ole Time	R <sub>L</sub> = 1 I	kΩ			20	28	n	S
			$C_L = 45$							
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Maximum Output Disa	ble lime	R <sub>L</sub> = 1				18	25	n	IS
ts	Minimum Set Up Time	Minimum Set Up Time		C <sub>L</sub> = 5 pF				5	n	S
з Н	Minimum Hold Time							10		S
tw	Minimum Pulse Width						9	16	n	S
V <sub>CC</sub> = 2.	Electrical Charac .0–6.0V, $C_L = 50 \text{ pF}$ , $t_r = t_f =$	6 ns (unless othe			T <sub>A</sub> =	25°C	T <sub>A</sub> = -40 to 8	35°C   T <sub>A</sub> = −55 to	125°C	
Symbol	Parameter	Conditio	ons	V <sub>CC</sub>	Тур		Guarante	ed Limits		Unit
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation	C <sub>L</sub> = 50 pF		2.0V	50	150	188	225		ns
	Delay, Data to Q	C <sub>L</sub> = 150 pF		2.0V	80	200	250	300		ns
		C <sub>L</sub> = 50 pF		4.5V	22	30	37	45		ns
		$C_L = 150 \text{ pF}$ $C_L = 50 \text{ pF}$		4.5V 6.0V	30 19	40 26	50 31	60 39		ns ns
		C <sub>L</sub> = 50 pF C <sub>L</sub> = 150 pF		6.0V	19 26	35	44	53		ns
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation	C <sub>L</sub> = 50 pF		2.0V	63	175	220	263		ns
	Delay, LE to Q	C <sub>L</sub> = 150 pF		2.0V	110	225	280	338		ns
		$C_L = 50 \text{ pF}$		4.5V	25	35	44	52		ns
		$C_L = 150 \text{ pF}$		4.5V	35	45	56	68		ns
		C <sub>L</sub> = 50 pF		6.0V	21	30	37		45	
t <sub>PZH</sub> , t <sub>PZL</sub>	Maximum Output	$C_L = 150 \text{ pF}$ $R_L = 1 \text{ k}\Omega$		6.0V	28	39	49	59		ns
PZH, PZL	Enable Time	$C_L = 50 \text{ pF}$		2.0V	50	150	188	225		ns
		C <sub>L</sub> = 150 pF		2.0V	80	200	250	300		ns
		$C_L = 50 \text{ pF}$		4.5V	21	30	37	45		ns
		$C_L = 150 \text{ pF}$		4.5V	30	40	50	60		ns
		C <sub>L</sub> = 50 pF		6.0V	19	26	31	39		ns
t t	Maximum Output Disable	C <sub>L</sub> = 150 pF R <sub>L</sub> = 1 kΩ		6.0V 2.0V	26 50	35 150	44	53 225		ns ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Disable Time	$C_L = 50 \text{ pF}$		2.0V 4.5V	21	30	37	45		ns
		- L F.		6.0V	19	26	31	39		ns
ts	Minimum Set Up Time			2.0V		50	60	75		ns
				4.5V		9	13	15		ns
	Minimum Hald T			6.0V		9	11	13		ns
t <sub>H</sub>	Minimum Hold Time			2.0V 4.5V		5 5	5 5	5 5		ns ns
				4.5V 6.0V		5	5	5		ns
t <sub>W</sub>	Minimum Pulse Width			2.0V	30	80	100	120		ns
				4.5V	10	16	20	24		ns
				6.0V	9	14	18	20		ns
t <sub>THL</sub> , t <sub>TLH</sub>	Maximum Output Rise	C <sub>L</sub> = 50 pF		2.0V	25	60	75	90		ns
	and Fall Time			4.5V 6.0V	7 6	12 10	15 13	18 15		ns ns
C <sub>PD</sub>	Power Dissipation	(per latch)		0.0 V	0	10	15	10		115
- רט	Capacitance (Note 5)	OC = V <sub>CC</sub>			30					pF
	· · · · · ·					1	1			
		OC = GND			50					pF

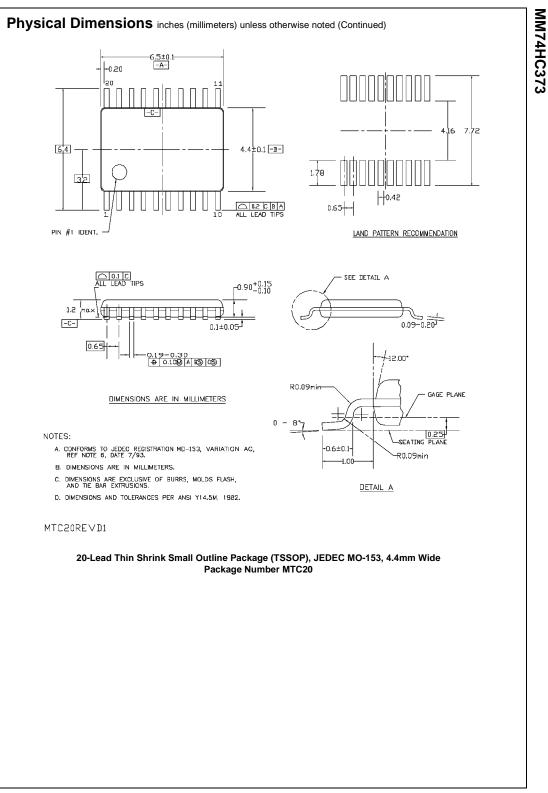
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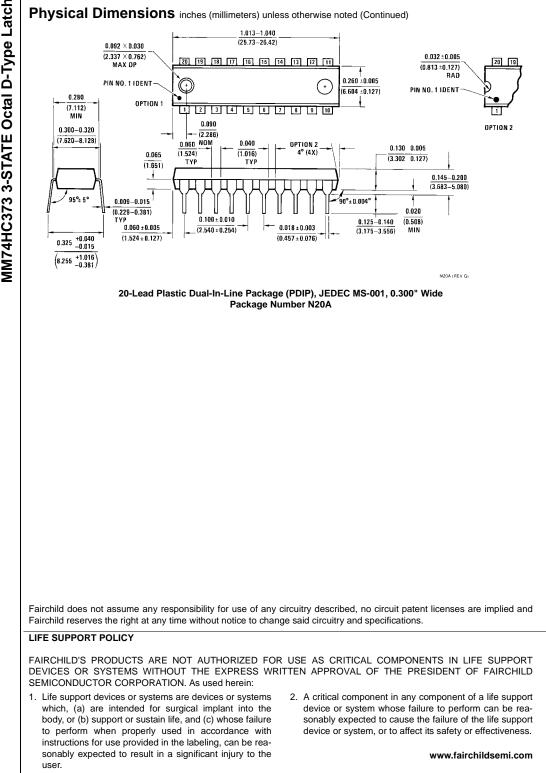
ACI	Electrical Characte	eristics (Cont	tinued)					
5 Symbol	Parameter	Conditions	Vcc	T <sub>A</sub> =	25°C	$T_A = -40$ to $85^{\circ}C$	$T_A = -55$ to $125^{\circ}C$	Units
<b>S</b>		Contaitionio		Тур		Guaranteed Limits		
C <sub>OUT</sub>	Maximum Output			15	20	20	20	pF
	Capacitance							

Note 5:  $C_{PD}$  determines the no load dynamic power consumption,  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ , and the no load dynamic current consumption,  $I_S = C_{PD} V_{CC} f + I_{CC}$ .









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